

Descriptions

The TS3USB30E is a bidirectional low-power dual port, high-speed, USB 2.0 analog switch with integrated protection for USB Type-C[™] systems. The device is configured as a dual 2:1 or 1:2 switch. It is optimized for use with the USB 2.0 DP/DM lines in a USB Type-C[™] system. The device is capable of true isolation. Even when COM+/- overrides VCC, very little current will flow back to the supply.

The TS3USB30E has low bit-to-bit skew and high channel-to-channel noise isolation, and is compatible with various standards, such as high-speed USB 2.0 (480Mbps). Each switch is bidirectional and offers little or no attenuation of the high-speed signals at the outputs. Its bandwidth is wide enough to pass high-speed USB 2.0 differential signals (480 Mb/s) with good signal integrity.

GPIO control of SEL 1.8V logic compatible. The TS3USB30E is available in both QFN 1418 and MSOP-10 with Pb-free and Halogen-free making it a perfect candidate for mobile and space constrained applications.

Features

- Low On-resistance, Ron=1.5Ω when VCC =5V
- 1.8V Logic Compatible Control Pin
- COM+/- Overrides VCC to Achieve True Isolation Even When Supply Is Dead
- High Off-Isolation: -100dB @ 100KHz
- Low Channel-to-Channel Crosstalk: -97dB @ 100KHz
- High Bandwidth (-3dB @800MHz) Suitable for USB2.0 High-Speed Routing
- Low Quiescent Current (<2uA) With Very Wide Supply Range (1.5V ~ 5.5V)

Applications

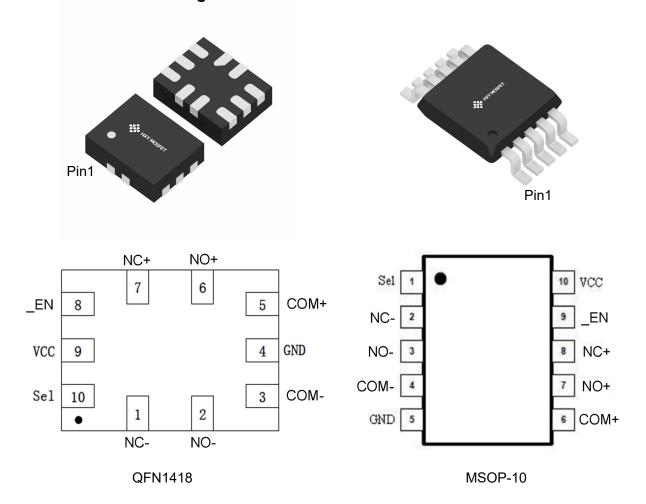
- Anywhere a USB Type-CTM or Micro-B Connector is Used
- Mobile Phones, Tablets and Notebooks

Order Information

Part Number	Package		
TS3USB30ERSWR	QFN1418	Tape and Reel	
TS3USB30EDGSR	MSOP -10	Tape and Reel	



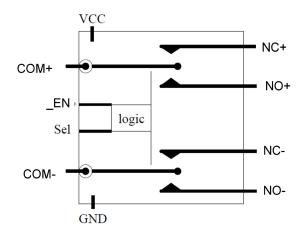
Function and Pin Configuration



Pin Nu	mber	Cumbal	Type	Descriptions
QFN1418	MSOP-10	Symbol		Descriptions
1	2	NC-	I/O	Negative Data Port (Normally closed)
2	3	NO-	I/O	Negative Data Port (Normally open)
3	4	COM-	I/O	Common Negative Data Port
4	5	GND	GND	Ground
5	6	COM+	I/O	Common Positive Data Port
6	7	NO+	I/O	Positive Data Port (Normally open)
7	8	NC+	I/O	Positive Data Port (Normally closed)
8	9	_EN	I	Chip Enable, Active Low
9	10	VCC	Supply	Power Supply
10	1	SEL	I	Logic Input Selection



Block Diagram



Truth Table

Input SEL	Function
0	COM+/- = NC+/-
1	COM+/- = NO+/-

Absolute Maximum Ratings (1)

Parameter	Symbol	Value	Unit
Supply Voltage	Vcc	-0.3 ~ 6.5	V
Control Input Voltage	V _{IN}	-0.3 ~ 6.5	V
Continuous Current Through NO, NC, COM		±100	mA
Peak Current Through NO, NC, COM (pulsed at 1ms 50% duty cycle)		±200	mA
Storage Temperature Range	T _{STG}	-55 ~ 150	°C
Junction Temperature under Bias	TJ	150	°C
Lead Temperature (Soldering, 10 seconds)	TL	260	°C
Power Dissipation	P _D	250	mW

Recommend operating ratings (2)

Parameter	Symbol	Value	Unit
Supply Voltage Operating	Vcc	1.5 ~ 5.5	V
Control Input Voltage	V _{IN}	-0.3 ~ 5.5	V
Input Signal Voltage	V _{COM}	-0.3 ~ 5.5	V
Operating Temperature	T _A	-40 ~ 85	οС
Thermal Resistance	$R_{\theta JA}$	360	oC/W

Note:

- "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied.
- The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.



DC Electronics Characteristics (Ta=25°C, VCC=3.3V, unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input logic high lovel	V	VCC: 3.3 ~ 5.5V	1.6			V
Input logic high level	V _{IH}	VCC: 1.5 ~ 3.3V	1.4			V
Input logic low lovel	W	VCC: 3.3 ~ 5.5V			0.6	V
Input logic low level	V _{IL}	VCC: 1.5 ~ 3.3V			0.4	V
Supply quiescent current	Icc	I _{COM} =0, V _{IN} =0 or V _{IN} =VCC			1.0	uA
Increase in L., per input	1	I _{COM} =0, VCC=4.5V			1.0	
Increase in I _{CC} per input	I _{CCT}	V _{IN} >1.8 or V _{IN} <0.5			1.0	uA
Off state leakage from	I _{COMx}	$V_{COM} = 5.5V$, $V_{NC(or NO)} = 0V$			±2.0	uA
COM_X to NC_X (or NO_X)	_					
	R _{ON1}	$V_{COM}=0 \sim 0.5V$, $I_{COM}=30mA$		3.0	3.5	Ω
On-Resistance	R _{ON2}	V_{COM} =0.5 ~ 2.0V, I_{COM} =30mA		3.6	3.9	Ω
OII-Resistance	R _{ON3}	$V_{COM}=2.0 \sim 4.0V, I_{COM}=30mA$		2.5	3.5	Ω
	R _{ON4}	V_{COM} =4.0 ~ 5.5V, I_{COM} =30mA		1.5	1.8	Ω
	R _{FLAT1}	V _{COM} =0 ~ 0.5V, I _{COM} =30mA		0.7		Ω
On Besistance Flatness	R _{FLAT2}	V _{COM} =0.5 ~ 2.0V, I _{COM} =30mA		0.5		Ω
On-Resistance Flatness	R _{FLAT3}	V_{COM} =2.0 ~ 4.0V, I_{COM} =30mA		1.6		Ω
	R _{FLAT4}	V _{COM} =4.0 ~ 5.5V, I _{COM} =30mA		0.3		Ω
On-Resistance Matching Between Channels	ΔR _{ON}	V _{COM} =0~5.5V, I _{COM} =30mA,		0.1	0.2	Ω

AC Electronics Characteristics (Ta=25°C, VCC=3.3V, unless otherwise noted)

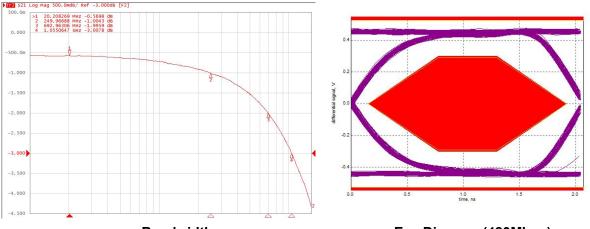
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Turn-On Time	T _{ON}	V_{COM} =1.5V, C_L =35pF, R_L =50 Ω		200		ns
Turn-Off Time	T _{OFF}	V_{COM} =1.5V, C_L =35pF, R_L =50 Ω		200		ns
Break-Before-Make time	T _{BBM}	V_{COM} =1.5V, C_L =35pF, R_L =50 Ω		500		ns
-3dB Bandwidth	BW	$R_L=50\Omega$, $C_L=0pF$		800		MHz
Officelation	OIDD	F=1KHz, R_L =50 Ω		-81		dB
Off isolation	OIRR	$F=10$ KHz, $R_L=50$ Ω		-80		dB
Caractalle	Vialli	F=1KHz, R _L =50Ω		-83		dB
Crosstalk	Xtalk	F=10KHz, R_L =50 Ω		-82		dB
Total Harmonic Distortion	TUD	F=20Hz to 20KHz		00		٩D
Total Harmonic Distortion	THD	V_{COM} =600m V p-p @ R_L =32 Ω ,	-80			dB

Capacitance (Ta=25°C, VCC=3.3V, unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Off capacitance	C _{OFF}	F=100KHz		5		pF
On capacitance	C _{ON}	F=100KHz		7		pF

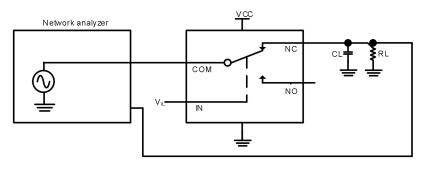


Typical Characteristics (Ta=25°C, VCC=3.3V, unless otherwise noted)

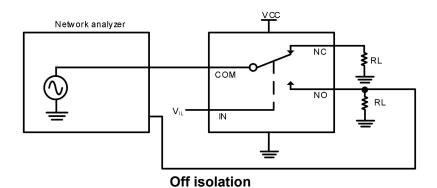




Eye Diagram (480Mbps)



Bandwidth



Network analyzer

COM1

NC1

COM2

NC2

VII.

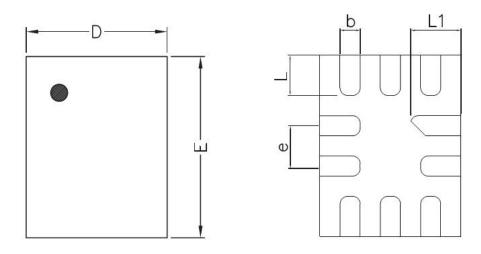
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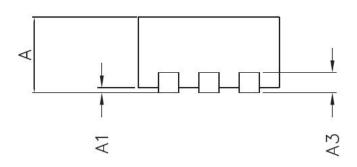
Crosstalk



Package Outline Dimensions

QFN1418

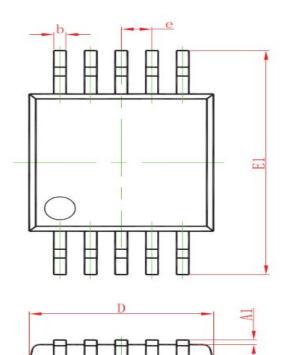


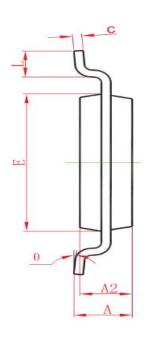


Symbol	Dimensio	n in Millimeters		
Symbol	Min.	Max.		
Α	0.450	0.550		
A1	0.000	0.050		
A3	0.1	52 Ref.		
D	1.350	1.450		
E	1.750 1.850			
b	0.150	0.250		
е	0.4	0.400 Typ.		
L	0.350	0.450		
L1	0.450	0.550		



MSOP-10





Symbol	Dimensio	n in Millimeters			
Symbol	Min.	Max.			
Α	0.820	1.100			
A1	0.020	0.150			
A2	0.750	0.950			
b	0.180	0.280			
С	0.090	0.230			
D	2.900	3.100			
е	0.5	0.50(BSC)			
E	2.900	3.100			
E1	4.750	5.050			
L	0.400	0.800			
θ	0°	6°			



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